









	<h2>STP8N65M5</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">STP8N65M5</a>
	<b>Hersteller / Marke:</b>	<a href="#">STMicroelectronics</a>
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 650V 7A TO-220
<b>Datenblätter:</b>	 <a href="#">STP8N65M5.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 23671 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">STP8N65M5</a>
Hersteller	<a href="#">STMicroelectronics</a>
Beschreibung	MOSFET N-CH 650V 7A TO-220
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	23671 pcs Stock
Serie	MDmesh™ V
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	70W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	650V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	7A (Tc)
Rds On (Max) @ Id, Vgs	600 mOhm @ 3.5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	690pF @ 100V
Verpackung	Tube




















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Anfrage STP8N65M5: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>STP8NA60FI</b> ST STP8NA60FI ST	 <b>STP8N90K5</b> STMicroelectronics N-CHANNEL 900 V, 0.60 OHM TYP.,	 <b>STP8N80K5</b> STMicroelectronics MOSFET N CH 800V 6A TO220	 <b>STP8703-TRG</b> SEMTRON-M SEMTRON-M SOT-23L
 <b>STP85NF55L</b> STMicroelectronics MOSFET N-CH 55V 80A TO-220	 <b>STP8NA50FI</b> STCHN STP8NA50FI STCHN	 <b>STP85NF55</b> STMicroelectronics MOSFET N-CH 55V 80A TO-220	 <b>STP8N90FI</b> ST STP8N90FI ST

### heiße Teile

Mehr

 STP80NF03L-04	 STP80NF03L04	 STP80NF05	 D STP80NF06	 STP80NF10
 STP80NF10FP	 STP80NF12	 D STP80NF55	 STP80NF55-06	 STP80NF55-06FP
 STP80NF55-08	 STP80NF55L-06	 STP80NF55L-08	 STP80NF70	 STP80NF75
 D STP80NF75L	 STP80NS04Z	 STP80NS04ZB	 STP80PF06	 STP80PF55
 STP85N3LH5	 STP85NF10	 STP85NF3LL	 STP85NF55	 STP85NF55L
 STP8N80K5	 STP8NA60FI	 D STP8NC50	 STP8NK100Z	 STP8NK80Z
 STP8NK80ZFP	 D STP8NM50FP	 STP8NM50N	 STP8NM60FP	 STP8NM60N
 STP8NM60ND	 STP8NS25	 STP8NS25FP	 STP90N4F3	 STP90N55F4
 STP90N6F6	 STP90NF03L	 STP90NS04ZC	 D STP9547S8RG	 STP95N04
 STP95N3LLH6	 STP95N4F3	 STP9NB50FP	 STP9NB60	 STP9NB60FP

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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